

Band

LTE4

5MHz

16QAM

High Frequency Substitution Measurement

UL Verification Services, Inc.

Company: Samsung

Project #: 15I20033

Date: 2/27/2015

Test Engineer: R.Alegre

Configuration: EUT Only

Location: Chamber A

Mode: LTE_16QAM Band 4 Fundamentals, 5MHz Bandwidth

Test Equipment:

Receiving: Horn T711, and Chamber A SMA Cables

Substitution: Horn T59, 4ft SMA Cable Warehouse

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Cable Loss (dB)	Antenna Gain (dBi)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch								
1712.50	10.07	V	0.9	8.2	17.41	30.0	-12.6	
1712.50	16.97	H	0.9	8.2	24.31	30.0	-5.7	
Mid Ch								
1732.50	9.96	V	0.9	8.2	17.23	30.0	-12.8	
1732.50	17.71	H	0.9	8.2	24.98	30.0	-5.0	
High Ch								
1752.50	10.17	V	0.9	8.1	17.37	30.0	-12.6	
1752.50	17.66	H	0.9	8.1	24.86	30.0	-5.1	

Band

LTE4

5MHz

QPSK

High Frequency Substitution Measurement

UL Verification Services, Inc.

Company:

Project #:

Date:

Test Engineer:

Configuration:

Location:

Mode:

Samsung

15I20033

2/27/2015

R.Alegre

EUT Only

Chamber A

LTE_QPSK Band 4 Fundamentals, 5MHz Bandwidth

Test Equipment:

Receiving: Horn T711, and Chamber A SMA Cables

Substitution: Horn T59, 4ft SMA Cable Warehouse

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Cable Loss (dB)	Antenna Gain (dBi)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch								
1712.50	10.96	V	0.9	8.2	18.30	30.0	-11.7	
1712.50	17.83	H	0.9	8.2	25.17	30.0	-4.8	
Mid Ch								
1732.50	10.92	V	0.9	8.2	18.19	30.0	-11.8	
1732.50	18.62	H	0.9	8.2	25.89	30.0	-4.1	
High Ch								
1752.50	10.93	V	0.9	8.1	18.13	30.0	-11.9	
1752.50	18.64	H	0.9	8.1	25.84	30.0	-4.2	

Band

LTE4

3MHz

16QAM

High Frequency Substitution Measurement
UL Verification Services, Inc.

Company: Samsung

Project #: 15I20033

Date: 2/27/2015

Test Engineer: R.Alegre

Configuration: EUT Only

Location: Chamber A

Mode: LTE_16QAM Band 4 Fundamentals, 3MHz Bandwidth

Test Equipment:

Receiving: Horn T711, and Chamber A SMA Cables

Substitution: Horn T59, 4ft SMA Cable Warehouse

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Cable Loss (dB)	Antenna Gain (dBi)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch								
1711.50	10.05	V	0.9	8.2	17.40	30.0	-12.6	
1711.50	16.98	H	0.9	8.2	24.33	30.0	-5.7	
Mid Ch								
1732.50	9.90	V	0.9	8.2	17.17	30.0	-12.8	
1732.50	17.69	H	0.9	8.2	24.96	30.0	-5.0	
High Ch								
1753.50	9.87	V	0.9	8.1	17.06	30.0	-12.9	
1753.50	17.68	H	0.9	8.1	24.87	30.0	-5.1	

Band

LTE4

3MHz

QPSK

High Frequency Substitution Measurement

UL Verification Services, Inc.

Company:

Samsung

Project #:

15I20033

Date:

2/27/2015

Test Engineer:

R.Alegre

Configuration:

EUT Only

Location:

Chamber A

Mode:

LTE_QPSK Band 4 Fundamentals, 3MHz Bandwidth

Test Equipment:

Receiving: Horn T711, and Chamber A SMA Cables

Substitution: Horn T59, 4ft SMA Cable Warehouse

f	SG reading	Ant. Pol.	Cable Loss	Antenna Gain	EIRP	Limit	Delta	Notes
MHz	(dBm)	(H/V)	(dB)	(dBi)	(dBm)	(dBm)	(dB)	
Low Ch								
1711.50	10.96	V	0.9	8.2	18.31	30.0	-11.7	
1711.50	17.84	H	0.9	8.2	25.19	30.0	-4.8	
Mid Ch								
1732.50	10.89	V	0.9	8.2	18.16	30.0	-11.8	
1732.50	18.61	H	0.9	8.2	25.88	30.0	-4.1	
High Ch								
1753.50	10.96	V	0.9	8.1	18.15	30.0	-11.8	
1753.50	18.67	H	0.9	8.1	25.86	30.0	-4.1	

Band

LTE4

1.4MHz

16QAM

High Frequency Substitution Measurement
UL Verification Services, Inc.

Company: Samsung

Project #: 15I20033

Date: 2/27/2015

Test Engineer: R.Alegre

Configuration: EUT Only

Location: Chamber A

Mode: LTE_16QAM Band 4 Fundamentals, 1.4MHz Bandwidth

Test Equipment:

Receiving: Horn T711, and Chamber A SMA Cables

Substitution: Horn T59, 4ft SMA Cable Warehouse

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Cable Loss (dB)	Antenna Gain (dBi)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch								
1710.70	9.88	V	0.9	8.2	17.15	30.0	-12.8	
1710.70	16.98	H	0.9	8.2	24.25	30.0	-5.7	
Mid Ch								
1732.50	9.87	V	0.9	8.2	17.14	30.0	-12.9	
1732.50	17.66	H	0.9	8.2	24.93	30.0	-5.1	
High Ch								
1754.30	10.14	V	0.9	8.1	17.33	30.0	-12.7	
1754.30	17.78	H	0.9	8.1	24.97	30.0	-5.0	

Band

LTE4

1.4MHz

QPSK

High Frequency Substitution Measurement

UL Verification Services, Inc.

Company:

Samsung

Project #:

15I20033

Date:

2/27/2015

Test Engineer:

R.Alegre

Configuration:

EUT Only

Location:

Chamber A

Mode:

LTE_QPSK Band 4 Fundamentals, 1.4MHz Bandwidth

Test Equipment:

Receiving: Horn T711, and Chamber A SMA Cables

Substitution: Horn T59, 4ft SMA Cable Warehouse

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Cable Loss (dB)	Antenna Gain (dBi)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch								
1710.70	10.79	V	0.9	8.2	18.06	30.0	-11.9	
1710.70	17.67	H	0.9	8.2	24.94	30.0	-5.1	
Mid Ch								
1732.50	10.75	V	0.9	8.2	18.02	30.0	-12.0	
1732.50	18.63	H	0.9	8.2	25.90	30.0	-4.1	
High Ch								
1754.30	11.08	V	0.9	8.1	18.27	30.0	-11.7	
1754.30	18.63	H	0.9	8.1	25.82	30.0	-4.2	

Band

Band 2

HSDPA

High Frequency Substitution Measurement
UL Verification Services, Inc. Chamber A

Company: Samsung
Project #: 15I20033
Date: 2/26/2015
Test Engineer: R. Alegre
Configuration: EUT only
Mode: HSDPA B2

Test Equipment:
Receiving: Horn T711, and Chamber A SMA Cables
Substitution: Horn T59 Substitution, 4ft SMA Cable Warehouse

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Cable Loss (dB)	Antenna Gain (dBi)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Notes
Low Ch								
1852.40	2.78	V	0.9	8.0	9.94	33.0	-23.1	
1852.40	17.47	H	0.9	8.0	24.63	33.0	-8.4	
Mid Ch								
1880.00	2.75	V	0.9	8.0	9.91	33.0	-23.1	
1880.00	17.38	H	0.9	8.0	24.54	33.0	-8.5	
High Ch								
1907.60	2.70	V	0.9	8.0	9.86	33.0	-23.1	
1907.60	17.36	H	0.9	8.0	24.52	33.0	-8.5	

Rev. 3.17.11
Note: For Band 4 EIRP limit is 30dBm

Band
Band 2
REL99

High Frequency Substitution Measurement
UL Verification Services, Inc. Chamber A

Company: Samsung
Project #: 15I20033
Date: 2/26/2015
Test Engineer: R. Alegre
Configuration: EUT only
Mode: REL99 B2

Test Equipment:
Receiving: Horn T711, and Chamber A SMA Cables
Substitution: Horn T59 Substitution, 4ft SMA Cable Warehouse

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Cable Loss (dB)	Antenna Gain (dBi)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Notes
Low Ch								
1852.40	2.76	V	0.9	8.0	9.92	33.0	-23.1	
1852.40	17.60	H	0.9	8.0	24.76	33.0	-8.2	
Mid Ch								
1880.00	2.77	V	0.9	8.0	9.93	33.0	-23.1	
1880.00	17.40	H	0.9	8.0	24.56	33.0	-8.4	
High Ch								
1907.60	2.66	V	0.9	8.0	9.82	33.0	-23.2	
1907.60	17.39	H	0.9	8.0	24.55	33.0	-8.5	

Rev. 3.17.11
Note: For Band 4 EIRP limit is 30dBm

Band Band 5 HSDPA	High Frequency Substitution Measurement UL Verification Services, Inc. Chamber A Company: Samsung Project #: 15I20033 Date: 2/25/2015 Test Engineer: R. Alegre Configuration: EUT only Mode: HSDPA B5 FUND Test Equipment: Receiving: Sunol T130, and 3m Chamber A N-type Cable Substitution: Dipole T273, 4ft SMA Cable Warehouse.								
	f	SG reading	Ant. Pol.	Cable Loss	Antenna Gain	ERP	Limit	Margin	Notes
	MHz	(dBm)	(H/V)	(dB)	(dBd)	(dBm)	(dBm)	(dB)	
	Low Ch								
	826.40	14.77	V	0.9	0.0	13.87	38.5	-24.6	
	826.40	22.04	H	0.9	0.0	21.14	38.5	-17.3	
	Mid Ch								
	836.60	13.57	V	0.9	0.0	12.67	38.5	-25.8	
	836.60	22.10	H	0.9	0.0	21.20	38.5	-17.2	
	High Ch								
	846.60	13.73	V	0.9	0.0	12.83	38.5	-25.6	
	846.60	22.10	H	0.9	0.0	21.20	38.5	-17.2	
Rev. 3.17.11 Note: For Band 13/17 ERP limit is 34.77dBm; For Band 26 limit is 50dBm									

Band Band 5 REL99	High Frequency Substitution Measurement UL Verification Services, Inc. Chamber A Company: Samsung Project #: 15I20033 Date: 2/25/2015 Test Engineer: R. Alegre Configuration: EUT only Mode: REL99 B5 FUND Test Equipment: Receiving: Sunol T130, and 3m Chamber A N-type Cable Substitution: Dipole T273, 4ft SMA Cable Warehouse.								
	f	SG reading	Ant. Pol.	Cable Loss	Antenna Gain	ERP	Limit	Margin	Notes
	MHz	(dBm)	(H/V)	(dB)	(dBd)	(dBm)	(dBm)	(dB)	
	Low Ch								
	826.40	15.65	V	0.9	0.0	14.75	38.5	-23.7	
	826.40	22.88	H	0.9	0.0	21.98	38.5	-16.5	
	Mid Ch								
	836.60	14.60	V	0.9	0.0	13.70	38.5	-24.7	
	836.60	22.35	H	0.9	0.0	21.45	38.5	-17.0	
	High Ch								
	846.60	13.93	V	0.9	0.0	13.03	38.5	-25.4	
	846.60	22.57	H	0.9	0.0	21.67	38.5	-16.8	
Rev. 3.17.11 Note: For Band 13/17 ERP limit is 34.77dBm; For Band 26 limit is 50dBm									

Band Band 4 HSDPA	High Frequency Substitution Measurement UL Verification Services, Inc. Company: Samsung Project #: 15I20033 Date: 2/27/2015 Test Engineer: R.Alegre Configuration: EUT Only Location: Chamber A Mode: HSDPA Band 4 Fundamentals Test Equipment: Receiving: Horn T711, and Chamber A SMA Cables Substitution: Horn T59, 4ft SMA Cable Warehouse							
	f	SG reading	Ant. Pol.	Cable Loss	Antenna Gain	EIRP	Limit	Delta
	MHz	(dBm)	(H/V)	(dB)	(dBi)	(dBm)	(dBm)	(dB)
	Notes							
	Low Ch							
	1712.40	10.20	V	0.9	8.3	17.55	30.0	-12.4
	1712.40	17.15	H	0.9	8.3	24.50	30.0	-5.5
	Mid Ch							
	1732.60	10.22	V	0.9	8.2	17.49	30.0	-12.5
	1732.60	18.10	H	0.9	8.2	25.37	30.0	-4.6
	High Ch							
	1752.60	10.51	V	0.9	8.1	17.70	30.0	-12.3
	1752.60	18.30	H	0.9	8.1	25.49	30.0	-4.5

Band

GSM1900

EGPRS

High Frequency Substitution Measurement

UL Verification Services, Inc. Chamber A

Company: Samsung

Project #: 15I20033

Date: 2/26/2015

Test Engineer: R. Alegre

Configuration: EUT only

Mode: EGPRS 1900

Test Equipment:

Receiving: Horn T711, and Chamber A SMA Cables

Substitution: Horn T59 Substitution, 4ft SMA Cable Warehouse

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Cable Loss (dB)	Antenna Gain (dBi)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Notes
Low Ch								
1850.20	16.71	V	0.9	8.0	23.87	33.0	-9.1	
1850.20	21.60	H	0.9	8.0	28.76	33.0	-4.2	
Mid Ch								
1880.00	15.91	V	0.9	8.0	23.07	33.0	-9.9	
1880.00	21.70	H	0.9	8.0	28.86	33.0	-4.1	
High Ch								
1909.80	16.15	V	0.9	8.0	23.31	33.0	-9.7	
1909.80	21.40	H	0.9	8.0	28.56	33.0	-4.4	

Rev. 3.17.11

Note: For Band 4 EIRP limit is 30dBm

11.2. FIELD STRENGTH OF SPURIOUS RADIATION

RULE PART(S)

FCC: §2.1053, §22.917, §24.238, §27.53

LIMIT

The power of any emission outside of the authorized operating frequency ranges must be attenuated below the transmitting power (P) by a factor of at least $43 + 10 \log (P)$ dB.

TEST PROCEDURE

For Cellular equipment - Compliance with these rules is based on the use of measurement instrumentation employing a resolution bandwidth of 100 kHz or greater. In the 1 MHz bands immediately outside and adjacent to the frequency block a resolution bandwidth of at least one percent of the emission bandwidth of the fundamental emission of the transmitter may be employed. A narrower resolution bandwidth is permitted in all cases to improve measurement accuracy provided the measured power is integrated over the full required measurement bandwidth (i.e. 100 kHz or 1 percent of emission bandwidth, as specified). The emission bandwidth is defined as the width of the signal between two points, one below the carrier center frequency and one above the carrier center frequency, outside of which all emissions are attenuated at least 26 dB below the transmitter power.

For PCS equipment - Compliance with these rules is based on the use of measurement instrumentation employing a resolution bandwidth of 1 MHz or greater. However, in the 1 MHz bands immediately outside and adjacent to the frequency block a resolution bandwidth of at least one percent of the emission bandwidth of the fundamental emission of the transmitter may be employed. A narrower resolution bandwidth is permitted in all cases to improve measurement accuracy provided the measured power is integrated over the full required measurement bandwidth (i.e. 1 MHz or 1 percent of emission bandwidth, as specified). The emission bandwidth is defined as the width of the signal between two points, one below the carrier center frequency and one above the carrier center frequency, outside of which all emissions are attenuated at least 26 dB below the transmitter power.

RESULTS

11.2.1. SPURIOUS RADIATION DATA

High Frequency Substitution Measurement UL Verification Services, Inc.										
Company:		Samsung								
Project #:		15I20033								
Date:		02/27/15								
Test Engineer:		O. Stoelting								
Configuration:		X-pos EUT w/ AC Charger + HS								
Mode:		LTE2_20M_16QAM								
		Chamber		Pre-amplifier		Filter		Limit		
		5m Chamber A		T343 8449B		Filter 1		Part 24		
Band	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
LTE2 20MHz 16QAM	Low Ch, 1860MHz									
	3.720	-18.5	V	3.0	35.4	1.0	-52.9	-13.0	-39.9	
	5.580	-15.2	V	3.0	34.7	1.0	-49.0	-13.0	-36.0	
	7.440	-12.8	V	3.0	34.9	1.0	-46.7	-13.0	-33.7	
	3.720	-13.2	H	3.0	35.4	1.0	-47.5	-13.0	-34.5	
	5.580	-15.2	H	3.0	34.7	1.0	-48.9	-13.0	-35.9	
	7.440	-12.1	H	3.0	34.9	1.0	-46.0	-13.0	-33.0	
	Mid Ch, 1880.0MHz									
	3.760	-17.1	V	3.0	35.3	1.0	-51.4	-13.0	-38.4	
	5.640	-16.0	V	3.0	34.7	1.0	-49.7	-13.0	-36.7	
	7.520	-11.4	V	3.0	34.9	1.0	-45.4	-13.0	-32.4	
	3.760	-14.1	H	3.0	35.3	1.0	-48.5	-13.0	-35.5	
	5.640	-15.0	H	3.0	34.7	1.0	-48.8	-13.0	-35.8	
	7.520	-12.6	H	3.0	34.9	1.0	-46.5	-13.0	-33.5	
	High Ch, 1900 MHz									
	3.800	-14.5	V	3.0	35.3	1.0	-48.8	-13.0	-35.8	
	5.700	-15.4	V	3.0	34.7	1.0	-49.1	-13.0	-36.1	
	7.600	-13.9	V	3.0	34.9	1.0	-47.9	-13.0	-34.9	
	3.800	-15.3	H	3.0	35.3	1.0	-49.6	-13.0	-36.6	
	5.700	-15.0	H	3.0	34.7	1.0	-48.7	-13.0	-35.7	
	7.600	-12.5	H	3.0	34.9	1.0	-46.4	-13.0	-33.4	
	Rev. 03.03.09									
	Note: No other emissions were detected above the system noise floor.									

High Frequency Substitution Measurement UL Verification Services, Inc.										
Company:	Samsung									
Project #:	15I20033									
Date:	02/27/15									
Test Engineer:	O. Stoelting									
Configuration:	X-pos EUT w/ AC Charger + HS									
Mode:	LTE2_20M_QPSK									
Chamber 5m Chamber A Pre-amplifier T343 8449B Filter Filter 1 Limit Part 24										
Band	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
LTE2	Low Ch, 1860MHz									
20MHz	3.720	-17.2	V	3.0	35.4	1.0	-51.6	-13.0	-38.6	
QPSK	5.580	-14.8	V	3.0	34.7	1.0	-48.5	-13.0	-35.5	
	7.440	-13.5	V	3.0	34.9	1.0	-47.4	-13.0	-34.4	
	3.720	-11.9	H	3.0	35.4	1.0	-46.3	-13.0	-33.3	
	5.580	-13.9	H	3.0	34.7	1.0	-47.6	-13.0	-34.6	
	7.440	-12.4	H	3.0	34.9	1.0	-46.3	-13.0	-33.3	
	Mid Ch, 1880.0MHz									
	3.760	-16.0	V	3.0	35.3	1.0	-50.3	-13.0	-37.3	
	5.640	-15.4	V	3.0	34.7	1.0	-49.1	-13.0	-36.1	
	7.520	-11.9	V	3.0	34.9	1.0	-45.9	-13.0	-32.9	
	3.760	-11.7	H	3.0	35.3	1.0	-46.0	-13.0	-33.0	
	5.640	-14.7	H	3.0	34.7	1.0	-48.4	-13.0	-35.4	
	7.520	-11.9	H	3.0	34.9	1.0	-45.9	-13.0	-32.9	
	High Ch, 1900 MHz									
	3.800	-13.4	V	3.0	35.3	1.0	-47.7	-13.0	-34.7	
	5.700	-15.0	V	3.0	34.7	1.0	-48.7	-13.0	-35.7	
	7.600	-13.1	V	3.0	34.9	1.0	-47.1	-13.0	-34.1	
	3.800	-11.2	H	3.0	35.3	1.0	-45.5	-13.0	-32.5	
	5.700	-14.7	H	3.0	34.7	1.0	-48.4	-13.0	-35.4	
	7.600	-12.3	H	3.0	34.9	1.0	-46.3	-13.0	-33.3	
Rev. 03.03.09										
Note: No other emissions were detected above the system noise floor.										

High Frequency Substitution Measurement UL Verification Services, Inc.										
Company:	Samsung									
Project #:	15I20033									
Date:	02/27/15									
Test Engineer:	O. Stoelting									
Configuration:	X-pos EUT w/ AC Charger + HS									
Mode:	LTE2_15M_16QAM									
Chamber 5m Chamber A Pre-amplifier T343 8449B Filter Filter 1 Limit Part 24										
Band	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
LTE2 15MHz 16QAM	Low Ch, 1857.5MHz									
	3.715	-17.3	V	3.0	35.4	1.0	-51.7	-13.0	-38.7	
	5.572	-14.7	V	3.0	34.7	1.0	-48.4	-13.0	-35.4	
	7.424	-9.9	V	3.0	34.9	1.0	-43.8	-13.0	-30.8	
	3.715	-10.4	H	3.0	35.4	1.0	-44.8	-13.0	-31.8	
	5.572	-17.0	H	3.0	34.7	1.0	-50.7	-13.0	-37.7	
	7.424	-12.9	H	3.0	34.9	1.0	-46.8	-13.0	-33.8	
	Mid Ch, 1880.0MHz									
	3.760	-16.4	V	3.0	35.3	1.0	-50.7	-13.0	-37.7	
	5.640	-16.2	V	3.0	34.7	1.0	-49.9	-13.0	-36.9	
	7.520	-15.3	V	3.0	34.9	1.0	-49.3	-13.0	-36.3	
	3.760	-6.0	H	3.0	35.3	1.0	-40.3	-13.0	-27.3	
	5.640	-17.3	H	3.0	34.7	1.0	-51.0	-13.0	-38.0	
	7.520	-15.1	H	3.0	34.9	1.0	-49.0	-13.0	-36.0	
	High Ch, 1902.5 MHz									
	3.805	-10.3	V	3.0	35.3	1.0	-44.6	-13.0	-31.6	
	5.707	-15.2	V	3.0	34.7	1.0	-49.0	-13.0	-36.0	
	7.610	-12.1	V	3.0	34.9	1.0	-46.0	-13.0	-33.0	
	3.805	-12.9	H	3.0	35.3	1.0	-47.2	-13.0	-34.2	
	5.707	-14.8	H	3.0	34.7	1.0	-48.6	-13.0	-35.6	
	7.610	-11.7	H	3.0	34.9	1.0	-45.7	-13.0	-32.7	
Rev. 03.03.09										
Note: No other emissions were detected above the system noise floor.										

High Frequency Substitution Measurement UL Verification Services, Inc.										
Company:	Samsung									
Project #:	15I20033									
Date:	02/27/15									
Test Engineer:	O. Stoelting									
Configuration:	X-pos EUT w/ AC Charger + HS									
Mode:	LTE2_15M_QPSK									
Chamber 5m Chamber A Pre-amplifier T343 8449B Filter Filter 1 Limit Part 24										
Band	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
LTE2	Low Ch, 1857.5MHz									
	3.715	-14.7	V	3.0	35.4	1.0	-49.0	-13.0	-36.0	
15MHz	5.572	-14.3	V	3.0	34.7	1.0	-48.0	-13.0	-35.0	
	7.424	-11.1	V	3.0	34.9	1.0	-45.0	-13.0	-32.0	
QPSK	3.715	-10.3	H	3.0	35.4	1.0	-44.7	-13.0	-31.7	
	5.572	-16.8	H	3.0	34.7	1.0	-50.5	-13.0	-37.5	
	7.424	-14.8	H	3.0	34.9	1.0	-48.7	-13.0	-35.7	
	Mid Ch, 1880.0MHz									
	3.760	-20.2	V	3.0	35.3	1.0	-54.5	-13.0	-41.5	
	5.640	-15.9	V	3.0	34.7	1.0	-49.6	-13.0	-36.6	
	7.520	-16.2	V	3.0	34.9	1.0	-50.2	-13.0	-37.2	
	3.760	-6.3	H	3.0	35.3	1.0	-40.6	-13.0	-27.6	
	5.640	-15.7	H	3.0	34.7	1.0	-49.4	-13.0	-36.4	
	7.520	-14.4	H	3.0	34.9	1.0	-48.4	-13.0	-35.4	
	High Ch, 1902.5 MHz									
	3.805	-10.6	V	3.0	35.3	1.0	-44.9	-13.0	-31.9	
	5.707	-14.8	V	3.0	34.7	1.0	-48.5	-13.0	-35.5	
	7.610	-13.3	V	3.0	34.9	1.0	-47.2	-13.0	-34.2	
	3.805	-14.8	H	3.0	35.3	1.0	-49.1	-13.0	-36.1	
	5.707	-14.5	H	3.0	34.7	1.0	-48.3	-13.0	-35.3	
	7.610	-12.0	H	3.0	34.9	1.0	-46.0	-13.0	-33.0	
Rev. 03.03.09										
Note: No other emissions were detected above the system noise floor.										

High Frequency Substitution Measurement UL Verification Services, Inc.										
Company:	Samsung									
Project #:	15I20033									
Date:	02/27/15									
Test Engineer:	O. Stoelting									
Configuration:	X-pos EUT w/ AC Charger + HS									
Mode:	LTE_10M_16QAM									
Chamber 5m Chamber A Pre-amplifier T343 8449B Filter Filter 1 Limit Part 24										
Band	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
LTE2	Low Ch, 1855.0MHz									
10MHz	3.710	-17.4	V	3.0	35.4	1.0	-51.8	-13.0	-38.8	
16QAM	5.565	-17.9	V	3.0	34.7	1.0	-51.6	-13.0	-38.6	
	7.420	-14.3	V	3.0	34.9	1.0	-48.2	-13.0	-35.2	
	3.710	-19.7	H	3.0	35.4	1.0	-54.1	-13.0	-41.1	
	5.565	-15.7	H	3.0	34.7	1.0	-49.5	-13.0	-36.5	
	7.420	-13.9	H	3.0	34.9	1.0	-47.8	-13.0	-34.8	
	Mid Ch, 1880.0MHz									
	3.760	-15.2	V	3.0	35.3	1.0	-49.6	-13.0	-36.6	
	5.640	-18.1	V	3.0	34.7	1.0	-51.8	-13.0	-38.8	
	7.520	-16.6	V	3.0	34.9	1.0	-50.5	-13.0	-37.5	
	3.760	-14.0	H	3.0	35.3	1.0	-48.3	-13.0	-35.3	
	5.640	-17.3	H	3.0	34.7	1.0	-51.1	-13.0	-38.1	
	7.520	-15.0	H	3.0	34.9	1.0	-49.0	-13.0	-36.0	
	High Ch, 1905 MHz									
	3.810	-15.5	V	3.0	35.3	1.0	-49.8	-13.0	-36.8	
	5.715	-17.4	V	3.0	34.7	1.0	-51.2	-13.0	-38.2	
	7.620	-15.8	V	3.0	34.9	1.0	-49.8	-13.0	-36.8	
	3.810	-18.0	H	3.0	35.3	1.0	-52.3	-13.0	-39.3	
	5.715	-16.6	H	3.0	34.7	1.0	-50.4	-13.0	-37.4	
	7.620	-14.7	H	3.0	34.9	1.0	-48.6	-13.0	-35.6	
Rev. 03.03.09										
Note: No other emissions were detected above the system noise floor.										

High Frequency Substitution Measurement UL Verification Services, Inc.										
Company:	Samsung									
Project #:	15I20033									
Date:	02/27/15									
Test Engineer:	O. Stoelting									
Configuration:	X-pos EUT w/ AC Charger + HS									
Mode:	LTE2_10M_QPSK									
Chamber 5m Chamber A Pre-amplifier T343 8449B Filter Filter 1 Limit Part 22										
Band	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
LTE2	Low Ch, 1855.0MHz									
10MHz	3.710	-16.1	V	3.0	35.4	1.0	-50.5	-13.0	-37.5	
QPSK	5.565	-17.4	V	3.0	34.7	1.0	-51.1	-13.0	-38.1	
	7.420	-9.9	V	3.0	34.9	1.0	-43.8	-13.0	-30.8	
	3.710	-19.0	H	3.0	35.4	1.0	-53.3	-13.0	-40.3	
	5.565	-17.6	H	3.0	34.7	1.0	-51.3	-13.0	-38.3	
	7.420	-14.7	H	3.0	34.9	1.0	-48.6	-13.0	-35.6	
	Mid Ch, 1880.0MHz									
	3.760	-16.7	V	3.0	35.3	1.0	-51.0	-13.0	-38.0	
	5.640	-16.0	V	3.0	34.7	1.0	-49.8	-13.0	-36.8	
	7.520	-15.5	V	3.0	34.9	1.0	-49.4	-13.0	-36.4	
	3.760	-14.5	H	3.0	35.3	1.0	-48.8	-13.0	-35.8	
	5.640	-17.6	H	3.0	34.7	1.0	-51.4	-13.0	-38.4	
	7.520	-14.5	H	3.0	34.9	1.0	-48.4	-13.0	-35.4	
	High Ch, 1905 MHz									
	3.810	-17.1	V	3.0	35.3	1.0	-51.4	-13.0	-38.4	
	5.715	-17.7	V	3.0	34.7	1.0	-51.4	-13.0	-38.4	
	7.620	-14.6	V	3.0	34.9	1.0	-48.5	-13.0	-35.5	
	3.810	-19.0	H	3.0	35.3	1.0	-53.3	-13.0	-40.3	
	5.715	-16.8	H	3.0	34.7	1.0	-50.5	-13.0	-37.5	
	7.620	-14.0	H	3.0	34.9	1.0	-48.0	-13.0	-35.0	
Rev. 03.03.09										
Note: No other emissions were detected above the system noise floor.										

High Frequency Substitution Measurement UL Verification Services, Inc.										
Company:	Samsung									
Project #:	15I20033									
Date:	02/27/15									
Test Engineer:	O. Stoelting									
Configuration:	X-pos EUT w/ AC Charger + HS									
Mode:	LTE2_5M_16QAM									
Chamber 5m Chamber A Pre-amplifier T343 8449B Filter Filter 1 Limit Part 24										
Band	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
LTE2 5MHz 16QAM	Low Ch, 1852.5MHz									
	3.705	-20.6	V	3.0	35.4	1.0	-55.0	-13.0	-42.0	
	5.557	-17.6	V	3.0	34.7	1.0	-51.3	-13.0	-38.3	
	7.410	-14.8	V	3.0	34.9	1.0	-48.7	-13.0	-35.7	
	3.705	-12.8	H	3.0	35.4	1.0	-47.2	-13.0	-34.2	
	5.557	-17.7	H	3.0	34.7	1.0	-51.4	-13.0	-38.4	
	7.410	-14.2	H	3.0	34.9	1.0	-48.2	-13.0	-35.2	
	Mid Ch, 1880.0MHz									
	3.760	-14.2	V	3.0	35.3	1.0	-48.5	-13.0	-35.5	
	5.640	-17.8	V	3.0	34.7	1.0	-51.5	-13.0	-38.5	
	7.520	-13.5	V	3.0	34.9	1.0	-47.4	-13.0	-34.4	
	3.760	-9.8	H	3.0	35.3	1.0	-44.1	-13.0	-31.1	
	5.640	-18.1	H	3.0	34.7	1.0	-51.8	-13.0	-38.8	
	7.520	-15.5	H	3.0	34.9	1.0	-49.4	-13.0	-36.4	
	High Ch, 1907.5 MHz									
	3.815	-10.7	V	3.0	35.3	1.0	-45.0	-13.0	-32.0	
	5.722	-16.4	V	3.0	34.7	1.0	-50.2	-13.0	-37.2	
	7.630	-15.0	V	3.0	34.9	1.0	-49.0	-13.0	-36.0	
	3.815	-12.0	H	3.0	35.3	1.0	-46.3	-13.0	-33.3	
	5.722	-17.6	H	3.0	34.7	1.0	-51.3	-13.0	-38.3	
	7.630	-14.8	H	3.0	34.9	1.0	-48.8	-13.0	-35.8	
Rev. 03.03.09										
Note: No other emissions were detected above the system noise floor.										

High Frequency Substitution Measurement UL Verification Services, Inc.										
Company:	Samsung									
Project #:	15I20033									
Date:	02/27/15									
Test Engineer:	O. Stoelting									
Configuration:	X-pos EUT w/ AC Charger + HS									
Mode:	LTE2_5M_QPSK									
Chamber Pre-amplifier Filter Limit 5m Chamber A T343 8449B Filter 1 Part 24										
Band	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
LTE2	Low Ch, 1852.5MHz									
	3.705	-18.9	V	3.0	35.4	1.0	-53.3	-13.0	-40.3	
5MHz	5.557	-18.0	V	3.0	34.7	1.0	-51.7	-13.0	-38.7	
	7.410	-14.3	V	3.0	34.9	1.0	-48.2	-13.0	-35.2	
QPSK	3.705	-12.5	H	3.0	35.4	1.0	-46.9	-13.0	-33.9	
	5.557	-17.0	H	3.0	34.7	1.0	-50.7	-13.0	-37.7	
	7.410	-15.7	H	3.0	34.9	1.0	-49.6	-13.0	-36.6	
	Mid Ch, 1880.0MHz									
	3.760	-12.9	V	3.0	35.3	1.0	-47.3	-13.0	-34.3	
	5.640	-17.6	V	3.0	34.7	1.0	-51.3	-13.0	-38.3	
	7.520	-13.8	V	3.0	34.9	1.0	-47.7	-13.0	-34.7	
	3.760	-13.8	H	3.0	35.3	1.0	-48.1	-13.0	-35.1	
	5.640	-17.3	H	3.0	34.7	1.0	-51.1	-13.0	-38.1	
	7.520	-14.6	H	3.0	34.9	1.0	-48.5	-13.0	-35.5	
	High Ch, 1907.5 MHz									
	3.815	-11.0	V	3.0	35.3	1.0	-45.3	-13.0	-32.3	
	5.722	-16.8	V	3.0	34.7	1.0	-50.5	-13.0	-37.5	
	7.630	-16.0	V	3.0	34.9	1.0	-50.0	-13.0	-37.0	
	3.815	-11.7	H	3.0	35.3	1.0	-46.0	-13.0	-33.0	
	5.722	-16.6	H	3.0	34.7	1.0	-50.4	-13.0	-37.4	
	7.630	-13.9	H	3.0	34.9	1.0	-47.9	-13.0	-34.9	
Rev. 03.03.09										
Note: No other emissions were detected above the system noise floor.										

High Frequency Substitution Measurement UL Verification Services, Inc.										
Company:	Samsung									
Project #:	15I20033									
Date:	02/27/15									
Test Engineer:	O. Stoelting									
Configuration:	X-pos EUT w/ AC Charger + HS									
Mode:	LTE2_3M_HARM_16QAM									
Chamber 5m Chamber A Pre-amplifier T343 8449B Filter Filter 1 Limit Part 24										
Band	f	SG reading	Ant. Pol.	Distance	Preamp	Filter	EIRP	Limit	Delta	Notes
	GHz	(dBm)	(H/V)	(m)	(dB)	(dB)	(dBm)	(dBm)	(dB)	
LTE2	Low Ch, 1851.5MHz									
	3.703	-14.6	V	3.0	35.4	1.0	-49.0	-13.0	-36.0	
3MHz	5.554	-18.4	V	3.0	34.7	1.0	-52.1	-13.0	-39.1	
	7.406	-14.6	V	3.0	34.9	1.0	-48.5	-13.0	-35.5	
16QAM	3.703	-19.6	H	3.0	35.4	1.0	-54.0	-13.0	-41.0	
	5.554	-16.8	H	3.0	34.7	1.0	-50.6	-13.0	-37.6	
	7.406	-14.7	H	3.0	34.9	1.0	-48.7	-13.0	-35.7	
	Mid Ch, 1880.0MHz									
	3.760	-12.3	V	3.0	35.3	1.0	-46.7	-13.0	-33.7	
	5.640	-17.7	V	3.0	34.7	1.0	-51.5	-13.0	-38.5	
	7.520	-16.4	V	3.0	34.9	1.0	-50.3	-13.0	-37.3	
	3.760	-9.3	H	3.0	35.3	1.0	-43.6	-13.0	-30.6	
	5.640	-17.5	H	3.0	34.7	1.0	-51.2	-13.0	-38.2	
	7.520	-14.8	H	3.0	34.9	1.0	-48.7	-13.0	-35.7	
	High Ch, 1908.5 MHz									
	3.817	-14.9	V	3.0	35.3	1.0	-49.2	-13.0	-36.2	
	5.725	-16.8	V	3.0	34.7	1.0	-50.5	-13.0	-37.5	
	7.634	-10.0	V	3.0	34.9	1.0	-44.0	-13.0	-31.0	
	3.817	-9.9	H	3.0	35.3	1.0	-44.2	-13.0	-31.2	
	5.725	-16.1	H	3.0	34.7	1.0	-49.8	-13.0	-36.8	
	7.634	-13.7	H	3.0	34.9	1.0	-47.7	-13.0	-34.7	
Rev. 03.03.09										
Note: No other emissions were detected above the system noise floor.										

High Frequency Substitution Measurement UL Verification Services, Inc.										
Company:	Samsung									
Project #:	15I20033									
Date:	02/27/15									
Test Engineer:	O. Stoelting									
Configuration:	X-pos EUT w/ AC Charger + HS									
Mode:	LTE2_3M_HARM_QPSK									
Chamber 5m Chamber A Pre-amplifier T343 8449B Filter Filter 1 Limit Part 24										
Band	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
LTE2	Low Ch, 1851.5MHz									
	3.703	-15.4	V	3.0	35.4	1.0	-49.8	-13.0	-36.8	
3MHz	5.554	-17.6	V	3.0	34.7	1.0	-51.3	-13.0	-38.3	
	7.406	-15.6	V	3.0	34.9	1.0	-49.5	-13.0	-36.5	
QPSK	3.703	-18.2	H	3.0	35.4	1.0	-52.6	-13.0	-39.6	
	5.554	-17.2	H	3.0	34.7	1.0	-50.9	-13.0	-37.9	
	7.406	-14.9	H	3.0	34.9	1.0	-48.8	-13.0	-35.8	
	Mid Ch, 1880.0MHz									
	3.760	-13.0	V	3.0	35.3	1.0	-47.4	-13.0	-34.4	
	5.640	-16.8	V	3.0	34.7	1.0	-50.5	-13.0	-37.5	
	7.520	-16.4	V	3.0	34.9	1.0	-50.4	-13.0	-37.4	
	3.760	-12.3	H	3.0	35.3	1.0	-46.7	-13.0	-33.7	
	5.640	-17.2	H	3.0	34.7	1.0	-50.9	-13.0	-37.9	
	7.520	-14.2	H	3.0	34.9	1.0	-48.2	-13.0	-35.2	
	High Ch, 1908.5 MHz									
	3.817	-16.6	V	3.0	35.3	1.0	-50.8	-13.0	-37.8	
	5.725	-17.5	V	3.0	34.7	1.0	-51.2	-13.0	-38.2	
	7.634	-10.9	V	3.0	34.9	1.0	-44.9	-13.0	-31.9	
	3.817	-9.9	H	3.0	35.3	1.0	-44.2	-13.0	-31.2	
	5.725	-16.8	H	3.0	34.7	1.0	-50.5	-13.0	-37.5	
	7.634	-14.6	H	3.0	34.9	1.0	-48.6	-13.0	-35.6	
Rev. 03.03.09										
Note: No other emissions were detected above the system noise floor.										

High Frequency Substitution Measurement UL Verification Services, Inc.										
Company:	Samsung									
Project #:	15I20033									
Date:	02/27/15									
Test Engineer:	O. Stoelting									
Configuration:	X-pos EUT w/ AC Charger + HS									
Mode:	LTE2_1.4M_HARM_16QAM									
Chamber Pre-amplifier Filter Limit 5m Chamber A T343 8449B Filter 1 Part 24										
Band LTE2 1.4MHz 16QAM	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch, 1850.7MHz										
	3.701	-13.2	V	3.0	35.4	1.0	-47.6	-13.0	-34.6	
	5.552	-15.1	V	3.0	34.7	1.0	-48.8	-13.0	-35.8	
	7.403	-12.9	V	3.0	34.9	1.0	-46.8	-13.0	-33.8	
	3.701	-7.5	H	3.0	35.4	1.0	-41.9	-13.0	-28.9	
	5.552	-16.6	H	3.0	34.7	1.0	-50.3	-13.0	-37.3	
	7.403	-15.0	H	3.0	34.9	1.0	-48.9	-13.0	-35.9	
Mid Ch, 1880.0MHz										
	3.760	-14.4	V	3.0	35.3	1.0	-48.7	-13.0	-35.7	
	5.640	-17.9	V	3.0	34.7	1.0	-51.6	-13.0	-38.6	
	7.520	-15.6	V	3.0	34.9	1.0	-49.5	-13.0	-36.5	
	3.760	-6.5	H	3.0	35.3	1.0	-40.9	-13.0	-27.9	
	5.640	-17.2	H	3.0	34.7	1.0	-51.0	-13.0	-38.0	
	7.520	-13.8	H	3.0	34.9	1.0	-47.8	-13.0	-34.8	
High Ch, 1909.3 MHz										
	3.819	-16.1	V	3.0	35.3	1.0	-50.4	-13.0	-37.4	
	5.728	-17.4	V	3.0	34.7	1.0	-51.2	-13.0	-38.2	
	7.637	-13.1	V	3.0	35.0	1.0	-47.0	-13.0	-34.0	
	3.819	-9.5	H	3.0	35.3	1.0	-43.8	-13.0	-30.8	
	5.728	-17.7	H	3.0	34.7	1.0	-51.4	-13.0	-38.4	
	7.637	-13.3	H	3.0	35.0	1.0	-47.2	-13.0	-34.2	
Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.										

High Frequency Substitution Measurement UL Verification Services, Inc.										
Company:	Samsung									
Project #:	15I20033									
Date:	02/27/15									
Test Engineer:	O. Stoelting									
Configuration:	X-pos EUT w/ AC Charger + HS									
Mode:	LTE2_1.4M_HARM_QPSK									
Chamber 5m Chamber A Pre-amplifier T343 8449B Filter Filter 1 Limit Part 24										
Band	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
LTE2	Low Ch, 1850.7MHz									
1.4MHz	3.701	-15.7	V	3.0	35.4	1.0	-50.1	-13.0	-37.1	
QPSK	5.552	-16.6	V	3.0	34.7	1.0	-50.4	-13.0	-37.4	
	7.403	-14.9	V	3.0	34.9	1.0	-48.8	-13.0	-35.8	
	3.701	-12.5	H	3.0	35.4	1.0	-46.9	-13.0	-33.9	
	5.552	-18.4	H	3.0	34.7	1.0	-52.1	-13.0	-39.1	
	7.403	-15.1	H	3.0	34.9	1.0	-49.0	-13.0	-36.0	
	Mid Ch, 1880.0MHz									
	3.760	-14.6	V	3.0	35.3	1.0	-48.9	-13.0	-35.9	
	5.640	-17.9	V	3.0	34.7	1.0	-51.6	-13.0	-38.6	
	7.520	-15.2	V	3.0	34.9	1.0	-49.1	-13.0	-36.1	
	3.760	-10.9	H	3.0	35.3	1.0	-45.2	-13.0	-32.2	
	5.640	-17.1	H	3.0	34.7	1.0	-50.9	-13.0	-37.9	
	7.520	-15.0	H	3.0	34.9	1.0	-49.0	-13.0	-36.0	
	High Ch, 1909.3 MHz									
	3.819	-15.3	V	3.0	35.3	1.0	-49.5	-13.0	-36.5	
	5.728	-17.1	V	3.0	34.7	1.0	-50.9	-13.0	-37.9	
	7.637	-15.3	V	3.0	35.0	1.0	-49.2	-13.0	-36.2	
	3.819	-9.9	H	3.0	35.3	1.0	-44.1	-13.0	-31.1	
	5.728	-17.6	H	3.0	34.7	1.0	-51.3	-13.0	-38.3	
	7.637	-14.5	H	3.0	35.0	1.0	-48.4	-13.0	-35.4	
Rev. 03.03.09										
Note: No other emissions were detected above the system noise floor.										

Compliance Certification Services

Above 1GHz High Frequency Substitution Measurement

Company:

Samsung

Project #:

15I20033

Date:

3/3/2015

Test Engineer:

Jude Semana

Configuration:

EUT , AC Adapter, Headset, X Position

Location:

Chamber G

Mode:

LTE_16QAM Band 4 Harmonics, 20MHz Bandwidth

	f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preampl (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Band LTE4 20MHz 16QAM	Low Ch, 1720									
	3440.00	-16.5	V	3.0	36.0	1.0	-51.6	-13.0	-38.6	
	5160.00	-13.8	V	3.0	35.4	1.0	-48.2	-13.0	-35.2	
	6880.00	-12.9	V	3.0	35.7	1.0	-47.5	-13.0	-34.5	
	3440.00	-16.8	H	3.0	36.0	1.0	-51.8	-13.0	-38.8	
	5160.00	-12.9	H	3.0	35.4	1.0	-47.3	-13.0	-34.3	
	6880.00	-11.1	H	3.0	35.7	1.0	-45.7	-13.0	-32.7	
	Mid Ch, 1732.5									
	3465.00	-16.5	V	3.0	36.0	1.0	-51.5	-13.0	-38.5	
	5197.50	-13.7	V	3.0	35.4	1.0	-48.1	-13.0	-35.1	
	6930.00	-12.6	V	3.0	35.7	1.0	-47.2	-13.0	-34.2	
	3465.00	-17.0	H	3.0	36.0	1.0	-52.1	-13.0	-39.1	
	5197.50	-12.5	H	3.0	35.4	1.0	-46.9	-13.0	-33.9	
	6930.00	-11.5	H	3.0	35.7	1.0	-46.2	-13.0	-33.2	
	High Ch, 1745									
	3490.00	-16.7	V	3.0	36.0	1.0	-51.7	-13.0	-38.7	
	5235.00	-13.5	V	3.0	35.4	1.0	-47.9	-13.0	-34.9	
	6980.00	-12.5	V	3.0	35.7	1.0	-47.2	-13.0	-34.2	
3490.00	-16.9	H	3.0	36.0	1.0	-51.9	-13.0	-38.9		
5235.00	-12.4	H	3.0	35.4	1.0	-46.8	-13.0	-33.8		
6980.00	-11.9	H	3.0	35.7	1.0	-46.5	-13.0	-33.5		

Compliance Certification Services

Above 1GHz High Frequency Substitution Measurement

Company:

Project #:

Date:

Test Engineer:

Configuration:

Location:

Mode:

Samsung

15I20033

3/3/2015

Jude Semana

EUT , AC Adapter, Headset, X Position

Chamber G

LTE_QPSK Band 4 Harmonics, 20MHz Bandwidth

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch, 1720									
3440.00	-16.3	V	3.0	36.0	1.0	-51.3	-13.0	-38.3	
5160.00	-13.6	V	3.0	35.4	1.0	-48.1	-13.0	-35.1	
6880.00	-12.2	V	3.0	35.7	1.0	-46.9	-13.0	-33.9	
3440.00	-17.0	H	3.0	36.0	1.0	-52.0	-13.0	-39.0	
5160.00	-13.0	H	3.0	35.4	1.0	-47.4	-13.0	-34.4	
6880.00	-11.0	H	3.0	35.7	1.0	-45.7	-13.0	-32.7	
Mid Ch, 1732.5									
3465.00	-17.4	V	3.0	36.0	1.0	-52.4	-13.0	-39.4	
5197.50	-13.6	V	3.0	35.4	1.0	-48.1	-13.0	-35.1	
6930.00	-13.2	V	3.0	35.7	1.0	-47.8	-13.0	-34.8	
3465.00	-16.7	H	3.0	36.0	1.0	-51.7	-13.0	-38.7	
5197.50	-12.4	H	3.0	35.4	1.0	-46.8	-13.0	-33.8	
6930.00	-11.4	H	3.0	35.7	1.0	-46.0	-13.0	-33.0	
High Ch, 1745									
3490.00	-17.1	V	3.0	36.0	1.0	-52.1	-13.0	-39.1	
5235.00	-12.7	V	3.0	35.4	1.0	-47.1	-13.0	-34.1	
6980.00	-13.2	V	3.0	35.7	1.0	-47.9	-13.0	-34.9	
3490.00	-16.1	H	3.0	36.0	1.0	-51.2	-13.0	-38.2	
5235.00	-12.6	H	3.0	35.4	1.0	-47.0	-13.0	-34.0	
6980.00	-10.9	H	3.0	35.7	1.0	-45.6	-13.0	-32.6	

Compliance Certification Services

Above 1GHz High Frequency Substitution Measurement

Company:

Project #:

Date:

Test Engineer:

Configuration:

Location:

Mode:

Samsung

15I20033

3/3/2015

Jude Semana

EUT , AC Adapter, Headset, X Position

Chamber G

LTE_16QAM Band 4 Harmonics, 15MHz Bandwidth

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch, 1717.5									
3435.00	-16.7	V	3.0	36.1	1.0	-51.7	-13.0	-38.7	
5152.50	-12.9	V	3.0	35.4	1.0	-47.4	-13.0	-34.4	
6870.00	-11.7	V	3.0	35.7	1.0	-46.4	-13.0	-33.4	
15MHz									
3435.00	-16.8	H	3.0	36.1	1.0	-51.8	-13.0	-38.8	
5152.50	-11.4	H	3.0	35.4	1.0	-45.9	-13.0	-32.9	
16QAM									
6870.00	0.0	H	3.0	35.7	1.0	-34.7	-13.0	-21.7	
Mid Ch, 1732.5									
3465.00	-16.0	V	3.0	36.0	1.0	-51.0	-13.0	-38.0	
5197.50	-13.5	V	3.0	35.4	1.0	-47.9	-13.0	-34.9	
6930.00	-12.4	V	3.0	35.7	1.0	-47.1	-13.0	-34.1	
3465.00	-15.8	H	3.0	36.0	1.0	-50.8	-13.0	-37.8	
5197.50	-13.3	H	3.0	35.4	1.0	-47.7	-13.0	-34.7	
6930.00	-11.0	H	3.0	35.7	1.0	-45.7	-13.0	-32.7	
High Ch, 1747.5									
3495.00	-16.1	V	3.0	36.0	1.0	-51.1	-13.0	-38.1	
5242.50	-13.6	V	3.0	35.4	1.0	-48.0	-13.0	-35.0	
6990.00	-12.4	V	3.0	35.7	1.0	-47.1	-13.0	-34.1	
3495.00	-16.7	H	3.0	36.0	1.0	-51.7	-13.0	-38.7	
5242.50	-12.9	H	3.0	35.4	1.0	-47.4	-13.0	-34.4	
6990.00	-11.0	H	3.0	35.7	1.0	-45.7	-13.0	-32.7	

Compliance Certification Services

Above 1GHz High Frequency Substitution Measurement

Company:

Project #:

Date:

Test Engineer:

Configuration:

Location:

Mode:

Samsung

15I20033

3/3/2015

Jude Semana

EUT , AC Adapter, Headset, X Position

Chamber G

LTE_QPSK Band 4 Harmonics, 15MHz Bandwidth

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preampl (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch, 1717.5									
LTE4	3435.00	-16.1	V	3.0	36.1	1.0	-51.1	-13.0	-38.1
	5152.50	-13.6	V	3.0	35.4	1.0	-48.1	-13.0	-35.1
	6870.00	-12.1	V	3.0	35.7	1.0	-46.7	-13.0	-33.7
15MHz	3435.00	-16.4	H	3.0	36.1	1.0	-51.4	-13.0	-38.4
	5152.50	-12.6	H	3.0	35.4	1.0	-47.0	-13.0	-34.0
	6870.00	-9.7	H	3.0	35.7	1.0	-44.3	-13.0	-31.3
Mid Ch, 1732.5									
QPSK	3465.00	-16.8	V	3.0	36.0	1.0	-51.8	-13.0	-38.8
	5197.50	-13.3	V	3.0	35.4	1.0	-47.7	-13.0	-34.7
	6930.00	-11.3	V	3.0	35.7	1.0	-46.0	-13.0	-33.0
	3465.00	-16.5	H	3.0	36.0	1.0	-51.5	-13.0	-38.5
	5197.50	-12.9	H	3.0	35.4	1.0	-47.3	-13.0	-34.3
	6930.00	-10.0	H	3.0	35.7	1.0	-44.7	-13.0	-31.7
High Ch, 1747.5									
	3495.00	-16.7	V	3.0	36.0	1.0	-51.7	-13.0	-38.7
	5242.50	-13.4	V	3.0	35.4	1.0	-47.8	-13.0	-34.8
	6990.00	-12.3	V	3.0	35.7	1.0	-47.0	-13.0	-34.0
	3495.00	-16.1	H	3.0	36.0	1.0	-51.1	-13.0	-38.1
	5242.50	-12.7	H	3.0	35.4	1.0	-47.2	-13.0	-34.2
	6990.00	-10.9	H	3.0	35.7	1.0	-45.6	-13.0	-32.6

Compliance Certification Services

Above 1GHz High Frequency Substitution Measurement

Configuration:

Project #:

Date:

Test Engineer:

Configuration:

Location:

Mode:

Samsung

15I20033

3/3/2015

Jude Semana

EUT , AC Adapter, Headset, X Position

Chamber G

LTE_16QAM Band 4 Harmonics, 10MHz Bandwidth

	f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamplifier (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Band	Low Ch, 1715									
	LTE4	3430.00	-17.2	V	3.0	36.1	1.0	-52.2	-13.0	-39.2
		5145.00	-13.2	V	3.0	35.4	1.0	-47.7	-13.0	-34.7
		6860.00	-12.7	V	3.0	35.7	1.0	-47.4	-13.0	-34.4
	10MHz	3430.00	-17.4	H	3.0	36.1	1.0	-52.4	-13.0	-39.4
		5145.00	-13.6	H	3.0	35.4	1.0	-48.0	-13.0	-35.0
	16QAM	6860.00	-11.6	H	3.0	35.7	1.0	-46.3	-13.0	-33.3
	Mid Ch, 1732.5									
		3465.00	-16.8	V	3.0	36.0	1.0	-51.8	-13.0	-38.8
		5197.50	-13.6	V	3.0	35.4	1.0	-48.1	-13.0	-35.1
		6930.00	-12.4	V	3.0	35.7	1.0	-47.1	-13.0	-34.1
		3465.00	-16.6	H	3.0	36.0	1.0	-51.6	-13.0	-38.6
		5197.50	-13.2	H	3.0	35.4	1.0	-47.6	-13.0	-34.6
		6930.00	-11.4	H	3.0	35.7	1.0	-46.1	-13.0	-33.1
	High Ch, 1750									
		3500.00	-16.7	V	3.0	36.0	1.0	-51.7	-13.0	-38.7
		5250.00	-13.4	V	3.0	35.4	1.0	-47.8	-13.0	-34.8
		7000.00	-12.4	V	3.0	35.7	1.0	-47.1	-13.0	-34.1
	3500.00	-17.2	H	3.0	36.0	1.0	-52.2	-13.0	-39.2	
	5250.00	-11.7	H	3.0	35.4	1.0	-46.2	-13.0	-33.2	
	7000.00	-11.5	H	3.0	35.7	1.0	-46.2	-13.0	-33.2	

Compliance Certification Services

Above 1GHz High Frequency Substitution Measurement

Configuration:

Project #:

Date:

Test Engineer:

Configuration:

Location:

Mode:

Samsung

15I20033

3/3/2015

Jude Semana

EUT , AC Adapter, Headset, X Position

Chamber G

LTE_QPSK Band 4 Harmonics, 10MHz Bandwidth

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch, 1715									
LTE4	3430.00	-17.1	V	3.0	36.1	1.0	-52.2	-13.0	-39.2
	5145.00	-13.9	V	3.0	35.4	1.0	-48.3	-13.0	-35.3
	6860.00	-12.8	V	3.0	35.7	1.0	-47.4	-13.0	-34.4
10MHz	3430.00	-17.1	H	3.0	36.1	1.0	-52.2	-13.0	-39.2
	5145.00	-13.5	H	3.0	35.4	1.0	-47.9	-13.0	-34.9
	6860.00	-11.2	H	3.0	35.7	1.0	-45.8	-13.0	-32.8
Mid Ch, 1732.5									
QPSK	3465.00	-16.4	V	3.0	36.0	1.0	-51.4	-13.0	-38.4
	5197.50	-13.9	V	3.0	35.4	1.0	-48.3	-13.0	-35.3
	6930.00	-14.2	V	3.0	35.7	1.0	-48.9	-13.0	-35.9
	3465.00	-16.6	H	3.0	36.0	1.0	-51.6	-13.0	-38.6
	5197.50	-13.0	H	3.0	35.4	1.0	-47.4	-13.0	-34.4
	6930.00	-11.8	H	3.0	35.7	1.0	-46.5	-13.0	-33.5
High Ch, 1750									
	3500.00	-16.9	V	3.0	36.0	1.0	-51.9	-13.0	-38.9
	5250.00	-13.5	V	3.0	35.4	1.0	-47.9	-13.0	-34.9
	7000.00	-13.2	V	3.0	35.7	1.0	-47.8	-13.0	-34.8
	3500.00	-16.2	H	3.0	36.0	1.0	-51.2	-13.0	-38.2
	5250.00	-13.1	H	3.0	35.4	1.0	-47.5	-13.0	-34.5
	7000.00	-11.1	H	3.0	35.7	1.0	-45.7	-13.0	-32.7

Compliance Certification Services

Above 1GHz High Frequency Substitution Measurement

Company:

Project #:

Date:

Test Engineer:

Configuration:

Location:

Mode:

Samsung

15I20033

3/3/2015

Jude Semana

EUT , AC Adapter, Headset, X Position

Chamber G

LTE_16QAM Band 4 Harmonics, 5MHz Bandwidth

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes	
Low Ch, 1712.5										
LTE4	3425.00	-15.2	V	3.0	36.1	1.0	-50.2	-13.0	-37.2	
	5137.50	-14.2	V	3.0	35.4	1.0	-48.6	-13.0	-35.6	
	6850.00	-12.8	V	3.0	35.7	1.0	-47.5	-13.0	-34.5	
5MHz	3425.00	-12.8	H	3.0	36.1	1.0	-47.8	-13.0	-34.8	
	5137.50	-13.4	H	3.0	35.4	1.0	-47.8	-13.0	-34.8	
16QAM	6850.00	-11.2	H	3.0	35.7	1.0	-45.9	-13.0	-32.9	
	Mid Ch, 1732.5									
	3465.00	-16.6	V	3.0	36.0	1.0	-51.6	-13.0	-38.6	
	5197.50	-13.3	V	3.0	35.4	1.0	-47.7	-13.0	-34.7	
	6930.00	-13.1	V	3.0	35.7	1.0	-47.8	-13.0	-34.8	
	3465.00	-14.2	H	3.0	36.0	1.0	-49.3	-13.0	-36.3	
	5197.50	-13.0	H	3.0	35.4	1.0	-47.5	-13.0	-34.5	
	6930.00	-11.5	H	3.0	35.7	1.0	-46.2	-13.0	-33.2	
	High Ch, 1752.5									
	3505.00	-17.0	V	3.0	36.0	1.0	-52.0	-13.0	-39.0	
	5257.50	-14.0	V	3.0	35.4	1.0	-48.4	-13.0	-35.4	
	7010.00	-13.2	V	3.0	35.7	1.0	-47.8	-13.0	-34.8	
	3505.00	-13.9	H	3.0	36.0	1.0	-48.9	-13.0	-35.9	
	5257.50	-12.9	H	3.0	35.4	1.0	-47.4	-13.0	-34.4	
	7010.00	-11.0	H	3.0	35.7	1.0	-45.7	-13.0	-32.7	

Compliance Certification Services

Above 1GHz High Frequency Substitution Measurement

Company:

Samsung

Project #:

15I20033

Date:

3/3/2015

Test Engineer:

Jude Semana

Configuration:

EUT , AC Adapter, Headset, X Position

Location:

Chamber G

Mode:

LTE_QPSK Band 4 Harmonics, 5MHz Bandwidth

	f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamplifier (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Band	Low Ch, 1712.5									
	3425.00	-14.4	V	3.0	36.1	1.0	-49.5	-13.0	-36.5	
	5137.50	-13.7	V	3.0	35.4	1.0	-48.2	-13.0	-35.2	
LTE4	6850.00	-12.8	V	3.0	35.7	1.0	-47.5	-13.0	-34.5	
5MHz	3425.00	-13.8	H	3.0	36.1	1.0	-48.9	-13.0	-35.9	
	5137.50	-13.6	H	3.0	35.4	1.0	-48.0	-13.0	-35.0	
	6850.00	-10.5	H	3.0	35.7	1.0	-45.2	-13.0	-32.2	
QPSK	Mid Ch, 1732.5									
	3465.00	-13.8	V	3.0	36.0	1.0	-48.8	-13.0	-35.8	
	5197.50	-14.0	V	3.0	35.4	1.0	-48.4	-13.0	-35.4	
	6930.00	-12.7	V	3.0	35.7	1.0	-47.4	-13.0	-34.4	
	3465.00	-14.3	H	3.0	36.0	1.0	-49.4	-13.0	-36.4	
	5197.50	-13.1	H	3.0	35.4	1.0	-47.5	-13.0	-34.5	
	6930.00	-11.2	H	3.0	35.7	1.0	-45.8	-13.0	-32.8	
	High Ch, 1752.5									
	3505.00	-16.7	V	3.0	36.0	1.0	-51.7	-13.0	-38.7	
	5257.50	-13.6	V	3.0	35.4	1.0	-48.0	-13.0	-35.0	
	7010.00	-13.2	V	3.0	35.7	1.0	-47.9	-13.0	-34.9	
	3505.00	-14.5	H	3.0	36.0	1.0	-49.6	-13.0	-36.6	
	5257.50	-13.8	H	3.0	35.4	1.0	-48.2	-13.0	-35.2	
	7010.00	-11.8	H	3.0	35.7	1.0	-46.5	-13.0	-33.5	

Compliance Certification Services

Above 1GHz High Frequency Substitution Measurement

Company:

Project #:

Date:

Test Engineer:

Configuration:

Location:

Mode:

Samsung

15I20033

3/3/2015

Jude Semana

EUT , AC Adapter, Headset, X Position

Chamber G

LTE_16QAM Band 4 Harmonics, 3MHz Bandwidth

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamplifier (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch, 1711.5									
3423.00	-17.0	V	3.0	36.1	1.0	-52.0	-13.0	-39.0	
5134.50	-14.8	V	3.0	35.4	1.0	-49.2	-13.0	-36.2	
6846.00	-11.4	V	3.0	35.7	1.0	-46.1	-13.0	-33.1	
3MHz									
3423.00	-12.4	H	3.0	36.1	1.0	-47.5	-13.0	-34.5	
5134.50	-14.0	H	3.0	35.4	1.0	-48.5	-13.0	-35.5	
6846.00	-11.2	H	3.0	35.7	1.0	-45.9	-13.0	-32.9	
16QAM									
Mid Ch, 1732.5									
3465.00	-17.2	V	3.0	36.0	1.0	-52.2	-13.0	-39.2	
5197.50	-13.2	V	3.0	35.4	1.0	-47.6	-13.0	-34.6	
6930.00	-12.7	V	3.0	35.7	1.0	-47.3	-13.0	-34.3	
3465.00	-16.5	H	3.0	36.0	1.0	-51.6	-13.0	-38.6	
5197.50	-13.7	H	3.0	35.4	1.0	-48.2	-13.0	-35.2	
6930.00	-11.3	H	3.0	35.7	1.0	-46.0	-13.0	-33.0	
High Ch, 1753.5									
3507.00	-16.6	V	3.0	36.0	1.0	-51.6	-13.0	-38.6	
5260.50	-13.1	V	3.0	35.4	1.0	-47.6	-13.0	-34.6	
7014.00	-11.8	V	3.0	35.7	1.0	-46.4	-13.0	-33.4	
3507.00	-15.0	H	3.0	36.0	1.0	-50.0	-13.0	-37.0	
5260.50	-13.3	H	3.0	35.4	1.0	-47.8	-13.0	-34.8	
7014.00	-11.3	H	3.0	35.7	1.0	-46.0	-13.0	-33.0	

Compliance Certification Services

bove 1GHz High Frequency Substitution Measureme

Company:

Project #:

Date:

Test Engineer:

Configuration:

Location:

Mode:

Samsung

15I20033

3/3/2015

Jude Semana

EUT , AC Adapter, Headset, X Position

Chamber G

LTE_QPSK Band 4 Harmonics, 3MHz Bandwidth

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamplifier (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch, 1711.5									
3423.00	-8.5	V	3.0	36.1	1.0	-43.5	-13.0	-30.5	
5134.50	-14.5	V	3.0	35.4	1.0	-48.9	-13.0	-35.9	
6846.00	-12.6	V	3.0	35.7	1.0	-47.3	-13.0	-34.3	
3423.00	-12.8	H	3.0	36.1	1.0	-47.9	-13.0	-34.9	
5134.50	-13.2	H	3.0	35.4	1.0	-47.6	-13.0	-34.6	
6846.00	-10.8	H	3.0	35.7	1.0	-45.5	-13.0	-32.5	
Mid Ch, 1732.5									
3465.00	-17.0	V	3.0	36.0	1.0	-52.0	-13.0	-39.0	
5197.50	-13.9	V	3.0	35.4	1.0	-48.4	-13.0	-35.4	
6930.00	-12.5	V	3.0	35.7	1.0	-47.1	-13.0	-34.1	
3465.00	-17.1	H	3.0	36.0	1.0	-52.1	-13.0	-39.1	
5197.50	-13.6	H	3.0	35.4	1.0	-48.0	-13.0	-35.0	
6930.00	-11.4	H	3.0	35.7	1.0	-46.1	-13.0	-33.1	
High Ch, 1753.5									
3507.00	-17.0	V	3.0	36.0	1.0	-52.0	-13.0	-39.0	
5260.50	-13.8	V	3.0	35.4	1.0	-48.2	-13.0	-35.2	
7014.00	-11.7	V	3.0	35.7	1.0	-46.4	-13.0	-33.4	
3507.00	-14.7	H	3.0	36.0	1.0	-49.7	-13.0	-36.7	
5260.50	-13.1	H	3.0	35.4	1.0	-47.5	-13.0	-34.5	
7014.00	-10.6	H	3.0	35.7	1.0	-45.3	-13.0	-32.3	

Band

LTE4

3MHz

QPSK

Compliance Certification Services

bove 1GHz High Frequency Substitution Measuremer

Company:

Project #:

Date:

Test Engineer:

Configuration:

Location:

Mode:

Samsung

15I20033

3/3/2015

Jude Semana

EUT , AC Adapter, Headset, X Position

Chamber G

LTE_16QAM Band 4 Harmonics, 1.4MHz Bandwidth

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preampl (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch, 1710.7									
3421.40	-12.3	V	3.0	36.1	1.0	-47.3	-13.0	-34.3	
5132.10	-14.5	V	3.0	35.4	1.0	-49.0	-13.0	-36.0	
6842.80	-11.2	V	3.0	35.7	1.0	-45.9	-13.0	-32.9	
3421.40	-9.0	H	3.0	36.1	1.0	-44.0	-13.0	-31.0	
5132.10	-13.9	H	3.0	35.4	1.0	-48.4	-13.0	-35.4	
6842.80	-11.8	H	3.0	35.7	1.0	-46.4	-13.0	-33.4	
Mid Ch, 1732.5									
3465.00	-14.8	V	3.0	36.0	1.0	-49.8	-13.0	-36.8	
5197.50	-14.0	V	3.0	35.4	1.0	-48.5	-13.0	-35.5	
6930.00	-11.4	V	3.0	35.7	1.0	-46.0	-13.0	-33.0	
3465.00	-10.3	H	3.0	36.0	1.0	-45.4	-13.0	-32.4	
5197.50	-13.3	H	3.0	35.4	1.0	-47.8	-13.0	-34.8	
6930.00	-11.1	H	3.0	35.7	1.0	-45.8	-13.0	-32.8	
High Ch, 1754.3									
3508.60	-15.6	V	3.0	36.0	1.0	-50.6	-13.0	-37.6	
5262.90	-12.8	V	3.0	35.4	1.0	-47.2	-13.0	-34.2	
7017.20	-9.5	V	3.0	35.7	1.0	-44.2	-13.0	-31.2	
3508.60	-15.8	H	3.0	36.0	1.0	-50.8	-13.0	-37.8	
5262.90	-12.3	H	3.0	35.4	1.0	-46.7	-13.0	-33.7	
7017.20	-10.3	H	3.0	35.7	1.0	-45.0	-13.0	-32.0	

Compliance Certification Services

Above 1GHz High Frequency Substitution Measurement

Company:

Project #:

Date:

Test Engineer:

Configuration:

Location:

Mode:

Samsung

15I20033

3/3/2015

Jude Semana

EUT , AC Adapter, Headset, X Position

Chamber G

LTE_QPSK Band 4 Harmonics, 1.4MHz Bandwidth

f MHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch, 1710.7									
3421.40	-11.9	V	3.0	36.1	1.0	-46.9	-13.0	-33.9	
5132.10	-13.9	V	3.0	35.4	1.0	-48.4	-13.0	-35.4	
6842.80	-11.6	V	3.0	35.7	1.0	-46.3	-13.0	-33.3	
3421.40	-9.4	H	3.0	36.1	1.0	-44.4	-13.0	-31.4	
5132.10	-13.9	H	3.0	35.4	1.0	-48.3	-13.0	-35.3	
6842.80	-9.9	H	3.0	35.7	1.0	-44.5	-13.0	-31.5	
Mid Ch, 1732.5									
3465.00	-15.3	V	3.0	36.0	1.0	-50.3	-13.0	-37.3	
5197.50	-13.6	V	3.0	35.4	1.0	-48.1	-13.0	-35.1	
6930.00	-11.6	V	3.0	35.7	1.0	-46.3	-13.0	-33.3	
3465.00	-9.8	H	3.0	36.0	1.0	-44.9	-13.0	-31.9	
5197.50	-14.1	H	3.0	35.4	1.0	-48.5	-13.0	-35.5	
6930.00	-10.7	H	3.0	35.7	1.0	-45.3	-13.0	-32.3	
High Ch, 1754.3									
3508.60	-15.1	V	3.0	36.0	1.0	-50.1	-13.0	-37.1	
5262.90	-13.5	V	3.0	35.4	1.0	-48.0	-13.0	-35.0	
7017.20	-9.8	V	3.0	35.7	1.0	-44.5	-13.0	-31.5	
3508.60	-16.3	H	3.0	36.0	1.0	-51.3	-13.0	-38.3	
5262.90	-12.8	H	3.0	35.4	1.0	-47.2	-13.0	-34.2	
7017.20	-10.8	H	3.0	35.7	1.0	-45.5	-13.0	-32.5	

UL Verification Services, Inc. Above 1GHz High Frequency Substitution Measurement									
Company:	Samsung								
Project #:	15I20033								
Date:	02/27/15								
Test Engineer:	O. Stoelting								
Configuration:	X-pos EUT w/ AC Charger + HS								
Mode:	HSDPA_B2								
Chamber Pre-amplifier Filter Limit 5m Chamber A T34 8449B Filter 1 Part 24									
f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch, 1852.4MHz									
3.705	-16.4	V	3.0	35.4	1.0	-50.8	-13.0	-37.8	
5.557	-16.4	V	3.0	34.7	1.0	-50.1	-13.0	-37.1	
7.410	-13.2	V	3.0	34.9	1.0	-47.1	-13.0	-34.1	
3.705	-17.5	H	3.0	35.4	1.0	-51.9	-13.0	-38.9	
5.557	-15.1	H	3.0	34.7	1.0	-48.8	-13.0	-35.8	
7.410	-12.0	H	3.0	34.9	1.0	-45.9	-13.0	-32.9	
Mid Ch, 1880MHz									
3.760	-17.6	V	3.0	35.3	1.0	-51.9	-13.0	-38.9	
5.640	-14.8	V	3.0	34.7	1.0	-48.6	-13.0	-35.6	
7.520	-12.9	V	3.0	34.9	1.0	-46.8	-13.0	-33.8	
3.760	-18.4	H	3.0	35.3	1.0	-52.7	-13.0	-39.7	
5.640	-15.9	H	3.0	34.7	1.0	-49.6	-13.0	-36.6	
7.520	-13.3	H	3.0	34.9	1.0	-47.2	-13.0	-34.2	
High Ch, 1907.6MHz									
3.815	-14.3	V	3.0	35.3	1.0	-48.6	-13.0	-35.6	
5.723	-15.0	V	3.0	34.7	1.0	-48.7	-13.0	-35.7	
7.630	-11.6	V	3.0	34.9	1.0	-45.6	-13.0	-32.6	
3.815	-15.1	H	3.0	35.3	1.0	-49.4	-13.0	-36.4	
5.723	-15.7	H	3.0	34.7	1.0	-49.4	-13.0	-36.4	
7.630	-10.5	H	3.0	34.9	1.0	-44.4	-13.0	-31.4	
Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.									

UL Verification Services, Inc. Above 1GHz High Frequency Substitution Measurement									
Company:	Samsung								
Project #:	15I20033								
Date:	03/03/15								
Test Engineer:	Jude Semana								
Configuration:	X-pos EUT w/ AC Charger + HS								
Mode:	REL99_B2								
Chamber 3m Chamber Pre-amplifier T34 8449B Filter Filter 1 Limit Part 24									
f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch, 1852.4MHz									
3.705	-18.2	V	3.0	35.4	1.0	-52.6	-13.0	-39.6	
5.557	-14.6	V	3.0	34.7	1.0	-48.4	-13.0	-35.4	
7.410	-11.9	V	3.0	34.9	1.0	-45.8	-13.0	-32.8	
3.705	-17.9	H	3.0	35.4	1.0	-52.3	-13.0	-39.3	
5.557	-12.9	H	3.0	34.7	1.0	-46.7	-13.0	-33.7	
7.410	-10.7	H	3.0	34.9	1.0	-44.6	-13.0	-31.6	
Mid Ch, 1880MHz									
3.760	-16.6	V	3.0	35.3	1.0	-51.0	-13.0	-38.0	
5.640	-13.5	V	3.0	34.7	1.0	-47.2	-13.0	-34.2	
7.520	-10.8	V	3.0	34.9	1.0	-44.7	-13.0	-31.7	
3.760	-17.1	H	3.0	35.3	1.0	-51.4	-13.0	-38.4	
5.640	-13.4	H	3.0	34.7	1.0	-47.1	-13.0	-34.1	
7.520	-10.0	H	3.0	34.9	1.0	-43.9	-13.0	-30.9	
High Ch, 1907.6MHz									
3.815	-16.4	V	3.0	35.3	1.0	-50.7	-13.0	-37.7	
5.723	-13.9	V	3.0	34.7	1.0	-47.7	-13.0	-34.7	
7.630	-11.0	V	3.0	34.9	1.0	-44.9	-13.0	-31.9	
3.815	-14.1	H	3.0	35.3	1.0	-48.3	-13.0	-35.3	
5.723	-12.5	H	3.0	34.7	1.0	-46.2	-13.0	-33.2	
7.630	-11.1	H	3.0	34.9	1.0	-45.1	-13.0	-32.1	
Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.									

UL Verification Services, Inc. Above 1GHz High Frequency Substitution Measurement										
Company:	Samsung									
Project #:	15I20033									
Date:	02/26/15									
Test Engineer:	O. Stoelting									
Configuration:	X-pos EUT w/ AC Charger + HS									
Mode:	HSDPA_B5									
Chamber 5m Chamber A Pre-amplifier T34 8449B Filter Filter 1 Limit Part 22										
	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Band Band 5 HSDPA	Low Ch, 826.4MHz									
	1.653	0.2	V	3.0	37.4	1.0	-36.1	-13.0	-23.1	
	2.479	-22.7	V	3.0	36.4	1.0	-58.0	-13.0	-45.0	
	3.306	-29.1	V	3.0	35.8	1.0	-63.9	-13.0	-50.9	
	1.653	-8.5	H	3.0	37.4	1.0	-44.9	-13.0	-31.9	
	2.479	-31.0	H	3.0	36.4	1.0	-66.4	-13.0	-53.4	
	3.306	-29.5	H	3.0	35.8	1.0	-64.3	-13.0	-51.3	
	Mid Ch, 836.6MHz									
	1.673	-16.5	V	3.0	37.3	1.0	-52.8	-13.0	-39.8	
	2.510	-28.3	V	3.0	36.4	1.0	-63.7	-13.0	-50.7	
	3.346	-29.1	V	3.0	35.8	1.0	-63.9	-13.0	-50.9	
	1.673	-8.9	H	3.0	37.3	1.0	-45.3	-13.0	-32.3	
	2.510	-32.4	H	3.0	36.4	1.0	-67.7	-13.0	-54.7	
	3.346	-29.5	H	3.0	35.8	1.0	-64.3	-13.0	-51.3	
	High Ch, 846.6MHz									
	1.693	-2.6	V	3.0	37.3	1.0	-38.9	-13.0	-25.9	
	2.540	-21.2	V	3.0	36.3	1.0	-56.5	-13.0	-43.5	
	3.386	-29.0	V	3.0	35.7	1.0	-63.7	-13.0	-50.7	
	1.693	-8.7	H	3.0	37.3	1.0	-45.0	-13.0	-32.0	
	2.540	-29.7	H	3.0	36.3	1.0	-65.1	-13.0	-52.1	
3.386	-29.6	H	3.0	35.7	1.0	-64.3	-13.0	-51.3		
Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.										

UL Verification Services, Inc. Above 1GHz High Frequency Substitution Measurement									
Company:	Samsung								
Project #:	15I20033								
Date:	02/26/15								
Test Engineer:	O. Stoelting								
Configuration:	X-pos EUT w/ AC Charger + HS								
Mode:	REL99_B5								
Chamber 5m Chamber A Pre-amplifier T34 8449B Filter Filter 1 Limit Part 22									
f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch, 826.4MHz									
1.653	-0.1	V	3.0	37.4	1.0	-36.5	-13.0	-23.5	
2.479	-26.0	V	3.0	36.4	1.0	-61.4	-13.0	-48.4	
3.306	-29.1	V	3.0	35.8	1.0	-63.9	-13.0	-50.9	
1.653	-8.8	H	3.0	37.4	1.0	-45.2	-13.0	-32.2	
2.479	-31.3	H	3.0	36.4	1.0	-66.7	-13.0	-53.7	
3.306	-29.5	H	3.0	35.8	1.0	-64.3	-13.0	-51.3	
Mid Ch, 836.6MHz									
1.673	-0.2	V	3.0	37.3	1.0	-36.5	-13.0	-23.5	
2.510	-21.5	V	3.0	36.4	1.0	-56.9	-13.0	-43.9	
3.346	-29.3	V	3.0	35.8	1.0	-64.0	-13.0	-51.0	
1.673	-7.5	H	3.0	37.3	1.0	-43.9	-13.0	-30.9	
2.510	-31.5	H	3.0	36.4	1.0	-66.8	-13.0	-53.8	
3.346	-29.5	H	3.0	35.8	1.0	-64.2	-13.0	-51.2	
High Ch, 846.6MHz									
1.693	-2.2	V	3.0	37.3	1.0	-38.5	-13.0	-25.5	
2.540	-23.3	V	3.0	36.3	1.0	-58.7	-13.0	-45.7	
3.386	-29.0	V	3.0	35.7	1.0	-63.7	-13.0	-50.7	
1.693	-8.8	H	3.0	37.3	1.0	-45.1	-13.0	-32.1	
2.540	-27.8	H	3.0	36.3	1.0	-63.1	-13.0	-50.1	
3.386	-29.5	H	3.0	35.7	1.0	-64.3	-13.0	-51.3	
Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.									

UL Verification Services, Inc. Above 1GHz High Frequency Substitution Measurement										
Company: Project #: Date: Test Engineer: Configuration: Mode:		Samsung 15I20033 02/27/15 O. Stoelting X-pos EUT w/ AC Charger + HS GSM 1900 EGPRS								
Chamber		Pre-amplifier		Filter		Limit				
5m Chamber A		T34 8449B		Filter 1		Part 24				
Band GSM19 00 EGPRS	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch, 1850.2MHz										
	3.700	-17.3	V	3.0	35.4	1.0	-51.7	-13.0	-38.7	
	5.551	-18.2	V	3.0	34.7	1.0	-51.9	-13.0	-38.9	
	7.401	-9.5	V	3.0	34.9	1.0	-43.4	-13.0	-30.4	
	3.700	-6.5	H	3.0	35.4	1.0	-40.9	-13.0	-27.9	
	5.551	-21.2	H	3.0	34.7	1.0	-54.9	-13.0	-41.9	
	7.401	-10.7	H	3.0	34.9	1.0	-44.6	-13.0	-31.6	
Mid Ch, 1880MHz										
	3.760	-12.3	V	3.0	35.3	1.0	-46.7	-13.0	-33.7	
	5.640	-16.8	V	3.0	34.7	1.0	-50.5	-13.0	-37.5	
	7.520	-8.8	V	3.0	34.9	1.0	-42.8	-13.0	-29.8	
	3.760	-5.0	H	3.0	35.3	1.0	-39.4	-13.0	-26.4	
	5.640	-21.1	H	3.0	34.7	1.0	-54.9	-13.0	-41.9	
	7.520	-12.0	H	3.0	34.9	1.0	-45.9	-13.0	-32.9	
High Ch, 1909.8MHz										
	3.820	-11.8	V	3.0	35.3	1.0	-46.1	-13.0	-33.1	
	5.729	-23.1	V	3.0	34.7	1.0	-56.9	-13.0	-43.9	
	7.639	-13.4	V	3.0	35.0	1.0	-47.3	-13.0	-34.3	
	3.820	-18.7	H	3.0	35.3	1.0	-52.9	-13.0	-39.9	
	5.729	-23.5	H	3.0	34.7	1.0	-57.2	-13.0	-44.2	
	7.639	-18.1	H	3.0	35.0	1.0	-52.0	-13.0	-39.0	
Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.										

UL Verification Services, Inc. Above 1GHz High Frequency Substitution Measurement									
Company: Project #: Date: Test Engineer: Configuration: Mode:		Samsung 15I20033 02/27/15 O. Stoelting X-pos EUT w/ AC Charger + HS GSM 1900 GPRS							
Chamber 5m Chamber A		Pre-amplifier T34 8449B		Filter Filter 1		Limit Part 24			
f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
Low Ch, 1850.2MHz									
3.700	-16.1	V	3.0	35.4	1.0	-50.5	-13.0	-37.5	
5.551	-19.8	V	3.0	34.7	1.0	-53.5	-13.0	-40.5	
7.401	-14.1	V	3.0	34.9	1.0	-48.0	-13.0	-35.0	
3.700	-10.7	H	3.0	35.4	1.0	-45.1	-13.0	-32.1	
5.551	-20.8	H	3.0	34.7	1.0	-54.5	-13.0	-41.5	
7.401	-19.3	H	3.0	34.9	1.0	-53.2	-13.0	-40.2	
Mid Ch, 1880MHz									
3.760	-11.3	V	3.0	35.3	1.0	-45.7	-13.0	-32.7	
5.640	-19.6	V	3.0	34.7	1.0	-53.4	-13.0	-40.4	
7.520	-9.4	V	3.0	34.9	1.0	-43.3	-13.0	-30.3	
3.760	-15.4	H	3.0	35.3	1.0	-49.7	-13.0	-36.7	
5.640	-18.4	H	3.0	34.7	1.0	-52.1	-13.0	-39.1	
7.520	-21.3	H	3.0	34.9	1.0	-55.2	-13.0	-42.2	
High Ch, 1909.8MHz									
3.820	-12.8	V	3.0	35.3	1.0	-47.1	-13.0	-34.1	
5.729	-19.6	V	3.0	34.7	1.0	-53.3	-13.0	-40.3	
7.639	-15.4	V	3.0	35.0	1.0	-49.4	-13.0	-36.4	
3.820	-23.7	H	3.0	35.3	1.0	-58.0	-13.0	-45.0	
5.729	-19.8	H	3.0	34.7	1.0	-53.6	-13.0	-40.6	
7.639	-16.4	H	3.0	35.0	1.0	-50.3	-13.0	-37.3	
Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.									

UL Verification Services, Inc.
Above 1GHz High Frequency Substitution Measurement

Company: Samsung
Project #: 15I20033
Date: 03/18/15
Test Engineer: Jude Semana
Configuration: X-pos EUT w/ AC Charger + HS
Mode: EGPRS850 Harm

Chamber	Pre-amplifier	Filter	Limit
3m Chamber	T34 8449B	Filter 1	Part 22

Band	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
GSM850	Low Ch, 824.2MHz									
	1.648	-25.5	V	3.0	37.4	1.0	-61.9	-13.0	-48.9	
	2.473	-20.7	V	3.0	36.4	1.0	-56.1	-13.0	-43.1	
	3.297	-20.4	V	3.0	35.8	1.0	-55.2	-13.0	-42.2	
	1.648	-26.4	H	3.0	37.4	1.0	-62.7	-13.0	-49.7	
	2.473	-22.0	H	3.0	36.4	1.0	-57.4	-13.0	-44.4	
	3.297	-20.9	H	3.0	35.8	1.0	-55.7	-13.0	-42.7	
	Mid Ch, 836.6MHz									
	1.673	-24.8	V	3.0	37.3	1.0	-61.1	-13.0	-48.1	
EGPRS	2.510	-21.0	V	3.0	36.4	1.0	-56.3	-13.0	-43.3	
	3.346	-20.6	V	3.0	35.8	1.0	-55.3	-13.0	-42.3	
	1.673	-26.0	H	3.0	37.3	1.0	-62.3	-13.0	-49.3	
	2.510	-22.5	H	3.0	36.4	1.0	-57.9	-13.0	-44.9	
	3.346	-20.8	H	3.0	35.8	1.0	-55.6	-13.0	-42.6	
	High Ch, 848.8MHz									
	1.698	-24.4	V	3.0	37.3	1.0	-60.7	-13.0	-47.7	
	2.547	-21.9	V	3.0	36.3	1.0	-57.3	-13.0	-44.3	
	3.395	-20.1	V	3.0	35.7	1.0	-54.8	-13.0	-41.8	
1.698	-24.3	H	3.0	37.3	1.0	-60.6	-13.0	-47.6		
2.547	-23.2	H	3.0	36.3	1.0	-58.6	-13.0	-45.6		
3.395	-20.2	H	3.0	35.7	1.0	-54.9	-13.0	-41.9		

Rev. 03.03.09
 Note: No other emissions were detected above the system noise floor.

UL Verification Services, Inc. Above 1GHz High Frequency Substitution Measurement										
Company: Samsung Project #: 15I20033 Date: 03/18/15 Test Engineer: Jude Semana Configuration: X-pos EUT w/ AC Charger + HS Mode: GPRS 850										
Chamber 5m Chamber A		Pre-amplifier T34 8449B		Filter Filter 1		Limit Part 22				
Band	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
GSM850 GPRS	Low Ch, 824.2MHz									
	1.648	-26.2	V	3.0	37.4	1.0	-62.6	-13.0	-49.6	
	2.473	-20.1	V	3.0	36.4	1.0	-55.5	-13.0	-42.5	
	3.297	-20.7	V	3.0	35.8	1.0	-55.5	-13.0	-42.5	
	1.648	-26.2	H	3.0	37.4	1.0	-62.6	-13.0	-49.6	
	2.473	-22.2	H	3.0	36.4	1.0	-57.5	-13.0	-44.5	
	3.297	-20.8	H	3.0	35.8	1.0	-55.6	-13.0	-42.6	
	Mid Ch, 836.6MHz									
	1.673	-26.0	V	3.0	37.3	1.0	-62.4	-13.0	-49.4	
	2.510	-21.4	V	3.0	36.4	1.0	-56.8	-13.0	-43.8	
	3.346	-20.3	V	3.0	35.8	1.0	-55.0	-13.0	-42.0	
	1.673	-26.2	H	3.0	37.3	1.0	-62.6	-13.0	-49.6	
	2.510	-22.7	H	3.0	36.4	1.0	-58.0	-13.0	-45.0	
	3.346	-20.2	H	3.0	35.8	1.0	-54.9	-13.0	-41.9	
	High Ch, 848.8MHz									
	1.698	-25.0	V	3.0	37.3	1.0	-61.3	-13.0	-48.3	
	2.547	-21.7	V	3.0	36.3	1.0	-57.0	-13.0	-44.0	
	3.395	-19.6	V	3.0	35.7	1.0	-54.3	-13.0	-41.3	
1.698	-25.5	H	3.0	37.3	1.0	-61.8	-13.0	-48.8		
2.547	-23.1	H	3.0	36.3	1.0	-58.4	-13.0	-45.4		
3.395	-19.7	H	3.0	35.7	1.0	-54.4	-13.0	-41.4		
Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.										